

STB60NF06L STP60NF06LFP

N-channel 60V - 0.012Ω - 60A - TO-220/D²PAK/TO-220FP STripFET™ II Power MOSFET

General features

Туре	V _{DSS}	R _{DS(on)}	I _D
STB60NF06L	60V	<0.014Ω	60
STP60NF06L	60V	<0.014Ω	60A
STP60NF06LFP	60V	<0.014Ω	60A ⁽¹⁾

- Refer to SOA for the max allowable current values on FP-type due to Rth value
- Exceptional dv/dt capability
- 100% avalanche tested
- Application oriented characterization
- 175°C operating range
- Low threshold drive

Description

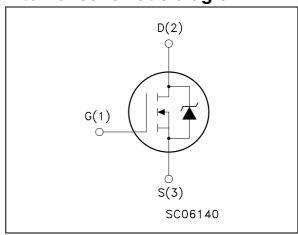
This Power MOSFET series realized with STMicroelectronics unique STripFET process has specifically been designed to minimize input capacitance and gate charge. It is therefore suitable as primary switch in advanced highefficiency isolated DC-DC converters for Telecom and Computer application. It is also intended for any application with low gate charge drive requirements.

Applications

■ Switching application

D²PAK TO-220FP

Internal schematic diagram



Order codes

Part number	Marking	Package	Packaging
STB60NF06LT4	B60NF06L	D ² PAK	Tape & reel
STP60NF06L	P60NF06L	TO-220	Tube
STP60NF06LFP	P60NF06LFP	TO-220FP	Tube

June 2006 Rev 3 1/16

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1 Electrical ratings

Table 1. Absolute maximum ratings

Symbol	Parameter	Va	Value		
		D ² PAK TO-220	TO-220FP		
V _{DS}	Drain-source voltage (V _{GS} = 0)	6	0	V	
V _{DGR}	Drain-gate voltage (R_{GS} = 20 kΩ)	6	0	V	
V _{GS}	Gate- source voltage	±	15	V	
I _D	Drain current (continuous) at T _C = 25°C	60	60 ⁽¹⁾	Α	
I _D	Drain current (continuous) at T _C = 100°C	42	42 ⁽¹⁾	Α	
I _{DM} ⁽²⁾	Drain current (pulsed)	240	240 ⁽¹⁾	Α	
P _{tot}	Total dissipation at T _C = 25°C	110	30	W	
	Derating Factor	0.73	0.2	W/°C	
dv/dt (3)	Peak diode recovery voltage slope	20 V/ns			
E _{AS} (4)	Single pulse avalanche energy	32	mJ		
V _{ISO}	Insulation withstand voltage (DC) 2000				
T _{stg}	Storage temperature	65 to 175		°C	
T _j	Max. operating junction temperature	65 to 175 °C			

- 1. Refer to SOA for the max allowable current values on FP-type due to Rth value
- 2. Pulse width limited by safe operating area.
- 3. $I_{SD} \leq 60A$, di/dt $\leq 600A/\mu s$, $V_{DD} \leq 48V$, $Tj \leq T_{JMAX}$
- 4. Starting Tj = 25 °C, I_D = 30A, V_{DD} = 30V

Table 2. Thermal data

			D ² PAK TO-220	TO-220FP	
Rthj-case	Thermal resistance junction-case	Max	1.36	5.0	°C/W
Rthj-amb Rthj-pcb T _I	Thermal resistance junction-ambient Thermal resistance junction-pcb ⁽¹⁾ Maximum lead temperature for soldering purpose	Max Max	62.5 35 300		°C/W °C/W °C

1. Only for SMD, When mounted on 1 inch2 FR-4 board, 2 oz of Cu.

2 Electrical characteristics

(T_{CASE}=25°C unless otherwise specified)

Table 3. On/off states

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V _{(BR)DSS}	Drain-source breakdown voltage	$I_D = 250 \mu A, V_{GS} = 0$	60			V
I _{DSS}	Zero gate voltage drain current (V _{GS} = 0)	V_{DS} = Max rating V_{DS} = Max rating, T_{C} = 125°C			1 10	μ Α μ Α
I _{GSS}	Gate-body leakage current (V _{DS} = 0)	V _{GS} = ± 15V			±100	nA
V _{GS(th)}	Gate threshold voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1			V
R _{DS(on)}	Static drain-source on resistance	$V_{GS} = 5V, I_D = 30A$ $V_{GS} = 10V, I_D = 30A$		0.014 0.012	0.016 0.014	Ω Ω

Table 4. Dynamic

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
9 _{fs} ⁽¹⁾	Forward transconductance	V _{DS} = 15V _, I _D = 30A		20		S
C _{iss} C _{oss} C _{rss}	Input capacitance Output capacitance Reverse transfer capacitance	$V_{DS} = 25V, f = 1MHz,$ $V_{GS} = 0$		2000 360 125		pF pF pF
$\begin{array}{c} t_{\text{d(on)}} \\ t_{\text{r}} \\ t_{\text{d(off)}} \\ t_{\text{f}} \end{array}$	Turn-on delay time Rise time Turn-off delay time Fall time	V_{DD} = 30V, I_D = 30A R_G = 4.7 Ω V_{GS} = 4.5V (see <i>Figure 15</i>)		35 220 55 30		ns ns ns
Q _g Q _{gs} Q _{gd}	Total gate charge Gate-source charge Gate-drain charge	V_{DD} = 48V, I_D = 60A, V_{GS} = 4.5V, R_G = 4.7 Ω (see <i>Figure 16</i>)		35 10 20	66	nC nC nC

^{1.} Pulsed: Pulse duration = 300 μs, duty cycle 1.5 %.

Table 5. Source drain diode

Symbol	Parameter Test conditions		Min.	Тур.	Max.	Unit
I _{SD}	Source-drain current Source-drain current (pulsed)				60 240	A A
V _{SD} ⁽²⁾	Forward on voltage	I _{SD} = 60A, V _{GS} = 0			1.3	V
t _{rr} Q _{rr} I _{RRM}	Reverse recovery time Reverse recovery charge Reverse recovery current	I_{SD} = 60A, di/dt = 100A/µs, V_{DD} = 30V, T_j = 150°C (see <i>Figure 17</i>)		110 250 4.5		ns nC A

^{1.} Pulse width limited by safe operating area.

^{2.} Pulsed: Pulse duration = 300 μ s, duty cycle 1.5 %

2.1 Electrical characteristics (curves)

Figure 1. Safe operating area

Figure 2. Thermal impedance

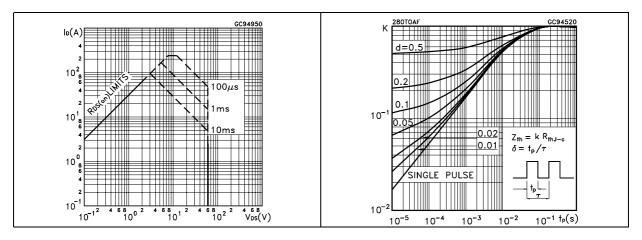


Figure 3. Safe operating area for TO-220FP

Figure 4. Thermal impedance for TO-220FP

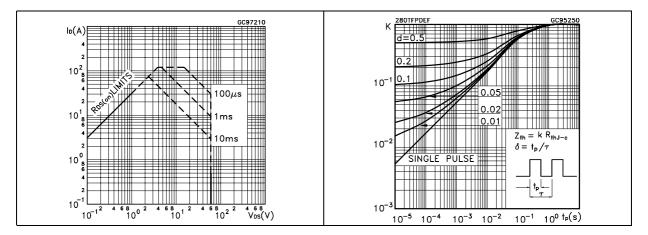
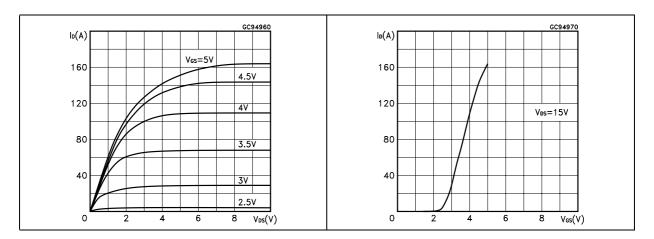


Figure 5. Output characterisics

Figure 6. Transfer characteristics



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Figure 7. Transconductance

Figure 8. Static drain-source on resistance

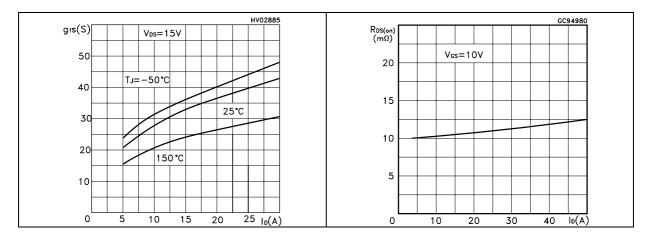


Figure 9. Gate charge vs gate-source voltage Figure 10. Capacitance variations

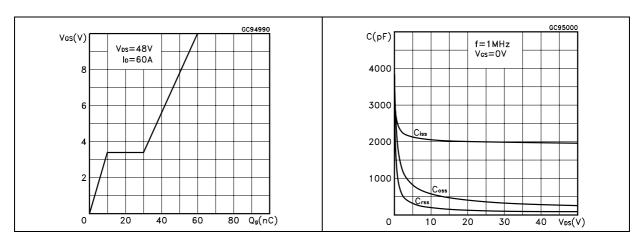
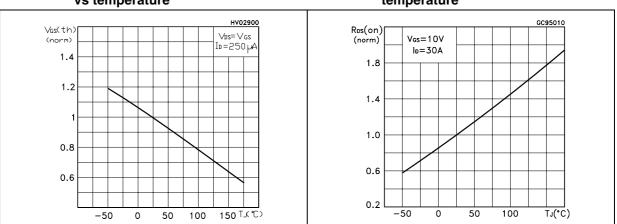


Figure 11. Normalized gate threshold voltage Figure 12. Normalized on resistance vs vs temperature temperature



0

10

Figure 13. Source-drain diode forward characteristics

Vsp(V)

1.4

1.2

TJ=-50°C

1

0.8

150°C

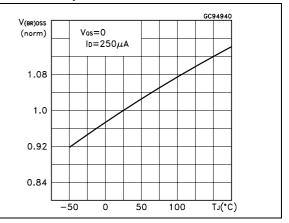
20

30

40

50 ID(A)

Figure 14. Normalized breakdown voltage temperature



3 Test circuit

Figure 15. Switching times test circuit for resistive load

Figure 16. Gate charge test circuit

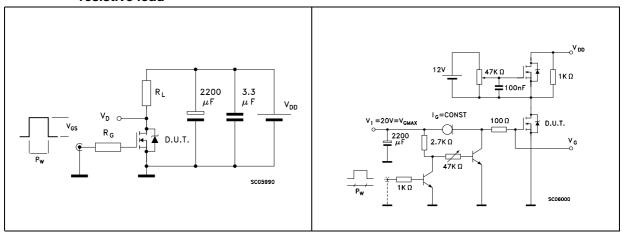


Figure 17. Test circuit for inductive load switching and diode recovery times

Figure 18. Unclamped Inductive load test circuit

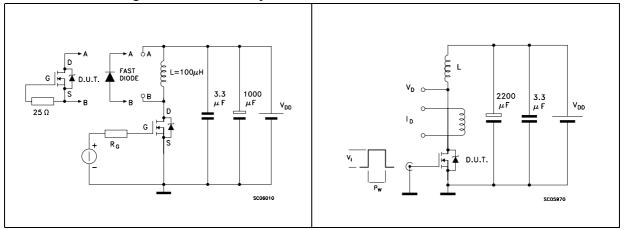
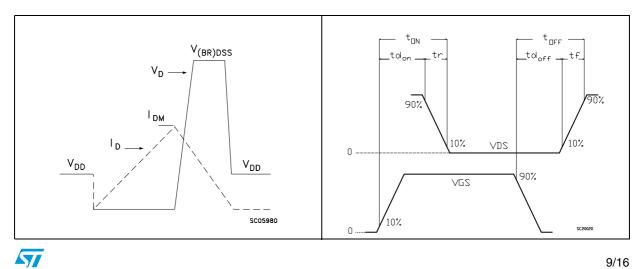


Figure 19. Unclamped inductive waveform

Figure 20. Switching time waveform



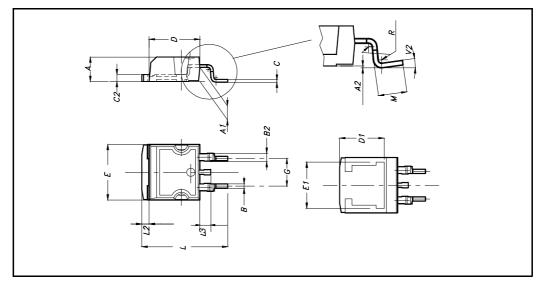
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4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

D²PAK MECHANICAL DATA

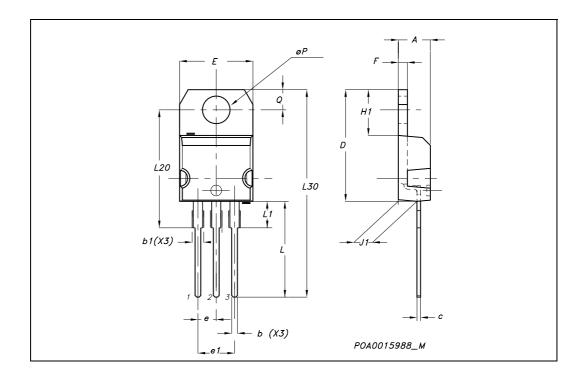
DIM	mm.			inch			
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
Α	4.4		4.6	0.173		0.181	
A1	2.49		2.69	0.098		0.106	
A2	0.03		0.23	0.001		0.009	
В	0.7		0.93	0.027		0.036	
B2	1.14		1.7	0.044		0.067	
С	0.45		0.6	0.017		0.023	
C2	1.23		1.36	0.048		0.053	
D	8.95		9.35	0.352		0.368	
D1		8			0.315		
Е	10		10.4	0.393			
E1		8.5			0.334		
G	4.88		5.28	0.192		0.208	
L	15		15.85	0.590		0.625	
L2	1.27		1.4	0.050		0.055	
L3	1.4		1.75	0.055		0.068	
М	2.4		3.2	0.094		0.126	
R		0.4			0.015		
V2	0 _δ		4º				



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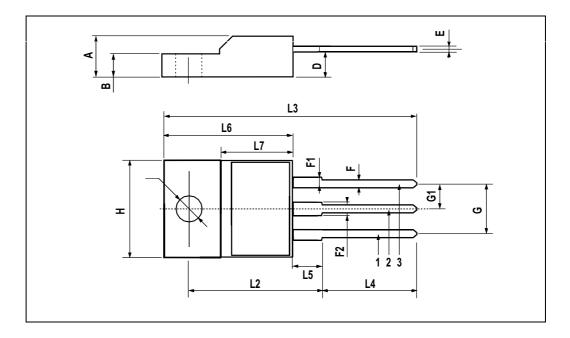
TO-220 MECHANICAL DATA

DIM.	mm.			inch			
DINI.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
Α	4.40		4.60	0.173		0.181	
b	0.61		0.88	0.024		0.034	
b1	1.15		1.70	0.045		0.066	
С	0.49		0.70	0.019		0.027	
D	15.25		15.75	0.60		0.620	
E	10		10.40	0.393		0.409	
е	2.40		2.70	0.094		0.106	
e1	4.95		5.15	0.194		0.202	
F	1.23		1.32	0.048		0.052	
H1	6.20		6.60	0.244		0.256	
J1	2.40		2.72	0.094		0.107	
L	13		14	0.511		0.551	
L1	3.50		3.93	0.137		0.154	
L20		16.40			0.645		
L30		28.90			1.137		
øΡ	3.75		3.85	0.147		0.151	
Q	2.65		2.95	0.104		0.116	



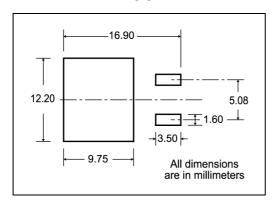
TO-220FP MECHANICAL DATA

DIM.	mm.					
DIIVI.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
Α	4.4		4.6	0.173		0.181
В	2.5		2.7	0.098		0.106
D	2.5		2.75	0.098		0.108
Е	0.45		0.7	0.017		0.027
F	0.75		1	0.030		0.039
F1	1.15		1.7	0.045		0.067
F2	1.15		1.7	0.045		0.067
G	4.95		5.2	0.195		0.204
G1	2.4		2.7	0.094		0.106
Н	10		10.4	0.393		0.409
L2		16			0.630	
L3	28.6		30.6	1.126		1.204
L4	9.8		10.6	.0385		0.417
L5	2.9		3.6	0.114		0.141
L6	15.9		16.4	0.626		0.645
L7	9		9.3	0.354		0.366
Ø	3		3.2	0.118		0.126

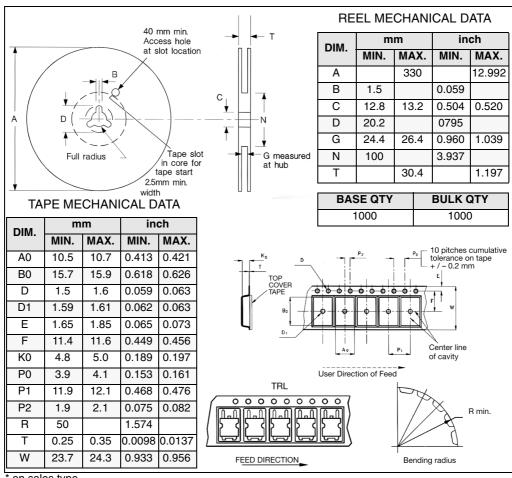


5 Packing mechanical data

D²PAK FOOTPRINT



TAPE AND REEL SHIPMENT



* on sales type

6 Revision history

Table 6. Revision history

Date	Revision	Changes
21-Jun-2004	2	Complete version
26-Jun-2006	3	New template, no content change

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